

10/535741

JC20 Rec'd PCT/PTO 18 MAY 2005
DOCKET NO.: 4878/PCT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE **NEW PCT NATIONAL PHASE PATENT APPLICATION**

OF: Seiji NAKAHATA et al.

USPS EXPRESS MAIL

USSN: TO BE ASSIGNED - new

EV 511 024 341 US

FILED: May 18, 2005

MAY 18 2005

FOR: Method of Processing Surface of Nitride
Semiconductor Crystal and Nitride
Semiconductor Crystal Obtained with
the Method

INTERNATIONAL SERIAL NO.: PCT/JP2004/008090

INTERNATIONAL FILING DATE: 03 June 2004

MS PCT

COMMISSIONER FOR PATENTS

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ALEXANDRIA, VA 22313-1450

May 18, 2005

PRELIMINARY AMENDMENT

Dear Sir:

Please amend the above identified patent application as follows.

[AMENDMENT FOLLOWS ON NEXT PAGE]